NTS0102-Q100

Dual supply translating transceiver; open drain; auto direction sensing

Rev. 1 — 27 February 2013

Product data sheet

1. General description

The NTS0102-Q100 is a 2-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two 2-bit input-output ports (An and Bn), one output enable input (OE) and two supply pins (V_{CC(A)} and V_{CC(B)}). V_{CC(A)} can be supplied at any voltage between 1.65 V and 3.6 V and V_{CC(B)} can be supplied at any voltage between 2.3 V and 5.5 V, making the device suitable for translating between any of the voltage nodes (1.8 V, 2.5 V, 3.3 V and 5.0 V). Pins An and OE are referenced to V_{CC(A)} and pins Bn are referenced to V_{CC(B)}. A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Wide supply voltage range:
 - ◆ V_{CC(A)}: 1.65 V to 3.6 V and V_{CC(B)}: 2.3 V to 5.5 V
- Maximum data rates:
 - Push-pull: 50 Mbps
- I_{OFF} circuitry provides partial Power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
 - ◆ MIL-STD-883, method 3015 Class 2 exceeds 2500 V for A port
 - ♦ MIL-STD-883, method 3015 Class 3B exceeds 8000 V for B port
 - HBM JESD22-A114E Class 2 exceeds 2500 V for A port
 - ◆ HBM JESD22-A114E Class 3B exceeds 8000 V for B port
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Multiple package options



Applications 3.

- I²C/SMBus
- UART
- GPIO

Ordering information 4.

Table 1. **Ordering information**

| Type number | Package | | | | | | | |
|----------------|------------------------|--------|--|----------|--|--|--|--|
| | Temperature range Name | | Description | Version | | | | |
| NTS0102DP-Q100 | –40 °C to +125 °C | TSSOP8 | plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm | SOT505-2 | | | | |
| NTS0102GD-Q100 | –40 °C to +125 °C | XSON8 | plastic extremely thin small outline package; no leads; 8 terminals; body $3 \times 2 \times 0.5$ mm | SOT996-2 | | | | |

Marking 5.

| Table 2. Marking | |
|------------------|--------------|
| Type number | Marking code |
| NTS0102DP-Q100 | s02 |
| NTS0102GD-Q100 | s02 |

Functional diagram 6.



7. Pinning information

7.1 Pinning



7.2 Pin description

| Table 3. | Pin description | |
|--------------------|-----------------|---|
| Symbol | Pin | Description |
| B2, B1 | 1, 8 | data input or output (referenced to $V_{CC(B)}$) |
| GND | 2 | ground (0 V) |
| V _{CC(A)} | 3 | supply voltage A |
| A2, A1 | 4, 5 | data input or output (referenced to $V_{CC(A)}$) |
| OE | 6 | output enable input (active HIGH; referenced to $V_{CC(A)}$) |
| V _{CC(B)} | 7 | supply voltage B |
| n.c. | - | not connected |
| | | |

8. Functional description

Table 4.Function table^[1]

| Supply voltage | | Input | Input/output | | | |
|---------------------------------------|--------------------|-------|-----------------|-----------------|--|--|
| V _{CC(A)} V _{CC(B)} | | OE | An | Bn | | |
| 1.65 V to $V_{CC(B)}$ | 2.3 V to 5.5 V | L | Z | Z | | |
| 1.65 V to $V_{CC(B)}$ | 2.3 V to 5.5 V | Н | input or output | output or input | | |
| GND ^[2] | GND ^[2] | Х | Z | Z | | |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] When either $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into power-down mode.

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9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Parameter | Conditions | Min | Max | Unit |
|-------------------------|---|---|--|--|
| Farameter | Conditions | | | Unit |
| supply voltage A | | -0.5 | +6.5 | V |
| supply voltage B | | -0.5 | +6.5 | V |
| input voltage | A port and OE input | <u>[1][2]</u> –0.5 | +6.5 | V |
| | B port | <u>[1][2]</u> –0.5 | +6.5 | V |
| output voltage | Active mode | [1][2] | | |
| | A or B port | -0.5 | $V_{CCO} + 0.5$ | V |
| | Power-down or 3-state mode | [1] | | |
| | A port | -0.5 | +4.6 | V |
| | B port | -0.5 | +6.5 | V |
| input clamping current | V ₁ < 0 V | -50 | - | mA |
| output clamping current | V _O < 0 V | -50 | - | mA |
| output current | $V_{O} = 0 V$ to V_{CCO} | [2] _ | ±50 | mA |
| supply current | I _{CC(A)} or I _{CC(B)} | - | 100 | mA |
| ground current | | -100 | - | mA |
| storage temperature | | -65 | +150 | °C |
| total power dissipation | $T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$ | [3] _ | 250 | mW |
| | supply voltage B input voltage output voltage input clamping current output clamping current output current supply current ground current storage temperature | $\begin{tabular}{ c c c } & \ & \ & \ & \ & \ & \ & \ & \ & \ & $ | supply voltage A-0.5supply voltage B-0.5input voltageA port and OE inputinput voltageA port and OE inputB port11/21 - 0.5output voltageActive modeA or B port-0.5Power-down or 3-state mode11A port-0.5B port-0.5B port-0.5Power-down or 3-state mode11A port-0.5B port-0.5B port-0.5B port-0.5Output clamping currentVI < 0 V | supply voltage A -0.5 +6.5 supply voltage B -0.5 +6.5 input voltage A port and OE input 112 -0.5 +6.5 B port 112 -0.5 +6.5 output voltage Active mode 112 -0.5 +6.5 output voltage Active mode 112 -0.5 +6.5 Power-down or 3-state mode 112 - - +6.5 Power-down or 3-state mode 111 - - +4.6 B port -0.5 +4.6 +6.5 Power-down or 3-state mode 111 - - +4.6 B port -0.5 +4.6 +6.5 Input clamping current V ₁ < 0 V |

[1] The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] V_{CCO} is the supply voltage associated with the output.

[3] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K. For XSON8 package: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions^{[1][2]}

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------|-------------------------------------|--|------|------|------|
| V _{CC(A)} | supply voltage A | | 1.65 | 3.6 | V |
| V _{CC(B)} | supply voltage B | | 2.3 | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| $\Delta t / \Delta V$ | input transition rise and fall rate | A or B port; push-pull driving | | | |
| | | $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$ | - | 10 | ns/V |
| | | OE input | | | |
| | | $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$ | - | 10 | ns/V |

[1] The A and B sides of an unused I/O pair must be held in the same state, both at V_{CCI} or both at GND.

[2] $V_{CC(A)}$ must be less than or equal to $V_{CC(B)}$.

11. Static characteristics

Table 7. Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = 25 °C.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|------------------------------|--|--|-----|-----|------|
| I | input leakage current | OE input; V _I = 0 V to 3.6 V; V _{CC(A)} = 1.65 V to 3.6 V; V _{CC(B)} = 2.3 V to 5.5 V | - | - | ±1 | μA |
| I _{OZ} | OFF-state output current | A or B port; V _O = 0 V or V _{CCO} ; V _{CC(A)} = 1.65 V to 3.6 V; V _{CC(B)} = 2.3 V to 5.5 V | <u>[1]</u> - | - | ±1 | μA |
| I _{OFF} | power-off leakage current | A port; V _I or V _O = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0 V to 5.5 V | $\begin{array}{cccc} & & & & & \\ t; V_{I} \mbox{ or } V_{O} = 0 \mbox{ V to } 3.6 \mbox{ V}; & & & & - & & \pm 1 \\ & & & & & \\ t; V_{I} \mbox{ or } V_{O} = 0 \mbox{ V to } 5.5 \mbox{ V}; & & & & - & & \pm 1 \end{array}$ | ±1 | μA | |
| | | B port; V _I or V _O = 0 V to 5.5 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0 V to 3.6 V | - | - | ±1 | μA |
| CI | input capacitance | OE input; $V_{CC(A)}$ = 3.3 V; $V_{CC(B)}$ = 3.3 V | - | 1 | - | рF |
| C _{I/O} | input/output | A port | - | 5 | - | pF |
| | capacitance | B port | - | 8.5 | - | pF |
| | | A or B port; $V_{CC(A)} = 3.3 \text{ V}$; $V_{CC(B)} = 3.3 \text{ V}$ | - | 11 | - | pF |

[1] V_{CCO} is the supply voltage associated with the output.

Table 8.Typical supply current

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T_{amb} = 25 °C.

| V _{CC(A)} | V _{CC(B)} | V _{CC(B)} | | | | | | | |
|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|----|--|--|
| | 2.5 V | | 3.3 V | 3.3 V | | | | | |
| | I _{CC(A)} | I _{CC(B)} | I _{CC(A)} | I _{CC(B)} | I _{CC(A)} | I _{CC(B)} | | | |
| 1.8 V | 0.1 | 0.5 | 0.1 | 1.5 | 0.1 | 4.6 | μΑ | | |
| 2.5 V | 0.1 | 0.1 | 0.1 | 0.8 | 0.1 | 3.8 | μΑ | | |
| 3.3 V | - | - | 0.1 | 0.1 | 0.1 | 2.8 | μΑ | | |

Table 9. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | –40 °C to | +85 °C | –40 °C to + | ⊦125 °C | Unit |
|-----------------|---------------|--|------------|------------------------|--------|------------------------|---------|------|
| | | | | Min | Max | Min | Max | |
| V _{IH} | HIGH-level | A port | | | | | | |
| | input voltage | $V_{CC(A)} = 1.65$ V to 1.95 V; $V_{CC(B)} = 2.3$ V to 5.5 V | <u>[1]</u> | $V_{CCI}-0.2$ | - | $V_{CCI} - 0.2$ | - | V |
| | | $V_{CC(A)} = 2.3 V \text{ to } 3.6 V;$ $V_{CC(B)} = 2.3 V \text{ to } 5.5 V$ | <u>[1]</u> | $V_{CCI}-0.4$ | - | $V_{\text{CCI}}-0.4$ | - | V |
| | | B port | | | | | | |
| | | $V_{CC(A)} = 1.65$ V to 3.6 V; $V_{CC(B)} = 2.3$ V to 5.5 V | <u>[1]</u> | $V_{CCI}-0.4$ | - | $V_{\text{CCI}}-0.4$ | - | V |
| | | OE input | | | | | | |
| | | $V_{CC(A)} = 1.65 V \text{ to } 3.6 V;$ $V_{CC(B)} = 2.3 V \text{ to } 5.5 V$ | | 0.65V _{CC(A)} | - | 0.65V _{CC(A)} | - | V |

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Table 9. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | _40 °C t | o +85 °C | –40 °C to | • +125 °C | Uni |
|------------------|-----------------------------|--|-----|---------------|------------------------|----------------------|------------------------|-----|
| | | | | Min | Max | Min | Max | 1 |
| VIL | LOW-level | A or B port | | | | | | |
| | input voltage | $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$ | | - | 0.15 | - | 0.15 | V |
| | | OE input | | | | | | |
| | | $V_{CC(A)} = 1.65 V \text{ to } 3.6 V;$ $V_{CC(B)} = 2.3 V \text{ to } 5.5 V$ | | - | 0.35V _{CC(A)} | - | 0.35V _{CC(A)} | V |
| V _{он} | HIGH-level | $I_O = -20 \ \mu A$ | | | | | | |
| | output voltage | $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$ | [2] | $0.67V_{CCO}$ | - | 0.67V _{CCO} | - | V |
| V _{OL} | LOW-level | A or B port; $I_0 = 1 \text{ mA}$ | [2] | | | | | |
| | output voltage | | | - | 0.4 | - | 0.4 | V |
| lı | input leakage current | $\begin{array}{l} \text{OE input; V}_{I} = 0 \ \text{V to } 3.6 \ \text{V;} \\ \text{V}_{\text{CC}(A)} = 1.65 \ \text{V to } 3.6 \ \text{V;} \\ \text{V}_{\text{CC}(B)} = 2.3 \ \text{V to } 5.5 \ \text{V} \end{array}$ | | - | ±2 | - | ±12 | μΑ |
| oz | OFF-state output current | A or B port; $V_O = 0$ V or V_{CCO} ; $V_{CC(A)} = 1.65$ V to 3.6 V; $V_{CC(B)} = 2.3$ V to 5.5 V | [2] | - | ±2 | - | ±12 | μA |
| I _{OFF} | power-off leakage | A port; V ₁ or V ₀ = 0 V to 3.6 V; V _{CC(A)} = 0 V; V _{CC(B)} = 0 V to 5.5 V | | - | ±2 | - | ±12 | μA |
| | current | B port; V ₁ or V ₀ = 0 V to 3.6 V; V _{CC(B)} = 0 V; V _{CC(A)} = 0 V to 3.6 V | | - | ±2 | - | ±12 | μA |
| I _{CC} | supply current | $V_I = 0 V \text{ or } V_{CCI}; I_O = 0 A$ | [1] | | | | | |
| | | I _{CC(A)} | | | | | | |
| | | $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$ | | - | 2.4 | - | 15 | μA |
| | | $V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$ | | - | 2.2 | - | 15 | μΑ |
| | | $V_{CC(A)} = 0 V; V_{CC(B)} = 5.5 V$ | | - | -1 | - | -8 | μΑ |
| | | I _{CC(B)} | | | | | | |
| | | $V_{CC(A)} = 1.65 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 2.3 \text{ V to } 5.5 \text{ V}$ | | - | 12 | - | 30 | μA |
| | | $V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$ | | - | -1 | - | -5 | μΑ |
| | | $V_{CC(A)} = 0 V; V_{CC(B)} = 5.5 V$ | | - | 1 | - | 6 | μΑ |
| | | $I_{CC(A)} + I_{CC(B)}$ | | | | | | |
| | | $V_{CC(A)} = 1.65 V \text{ to } 3.6 V;$ $V_{CC(B)} = 2.3 V \text{ to } 5.5 V$ | | - | 14.4 | - | 30 | μA |

[1] V_{CCI} is the supply voltage associated with the input.

[2] V_{CCO} is the supply voltage associated with the output.

12. Dynamic characteristics

Table 10. Dynamic characteristics for temperature range –40 °C to +85 °C^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6; for wave forms see Figure 4 and Figure 5.

| Symbol | Parameter | Conditions | | | | Vc | C(B) | | | |
|--------------------|-------------------------------|---------------------------|-----|-------------------|------|---------|---------|---------|---------|------|
| | | | | $2.5 V \pm 0.2 V$ | | 3.3 V : | ± 0.3 V | 5.0 V : | ± 0.5 V | |
| | | | | Min | Max | Min | Max | Min | Max | _ |
| $V_{CC(A)} =$ | 1.8 V ± 0.15 V | | | | | | | I | | |
| t _{PHL} | HIGH to LOW propagation delay | A to B | | - | 4.6 | - | 4.7 | - | 5.8 | ns |
| t _{PLH} | LOW to HIGH propagation delay | A to B | | - | 6.8 | - | 6.8 | - | 7.0 | ns |
| t _{PHL} | HIGH to LOW propagation delay | B to A | | - | 4.4 | - | 4.5 | - | 4.7 | ns |
| t _{PLH} | LOW to HIGH propagation delay | B to A | | - | 5.3 | - | 4.5 | - | 0.5 | ns |
| t _{en} | enable time | OE to A; B | | - | 200 | - | 200 | - | 200 | ns |
| t _{dis} | disable time | OE to A; no external load | [2] | - | 25 | - | 25 | - | 25 | ns |
| | | OE to B; no external load | [2] | - | 25 | - | 25 | - | 25 | ns |
| | | OE to A | | - | 230 | - | 230 | - | 230 | ns |
| | | OE to B | | - | 200 | - | 200 | - | 200 | ns |
| t _{TLH} | LOW to HIGH | A port | | 3.2 | 9.5 | 2.3 | 9.3 | 1.8 | 7.6 | ns |
| | output transition time | B port | | 3.3 | 10.8 | 2.7 | 9.1 | 2.7 | 7.6 | ns |
| t⊤⊣∟ | HIGH to LOW | A port | | 2.0 | 5.9 | 1.9 | 6.0 | 1.7 | 13.3 | ns |
| | output transition time | B port | | 2.9 | 7.6 | 2.8 | 7.5 | 2.8 | 10.0 | ns |
| t _{sk(o)} | output skew time | between channels | [3] | - | 0.7 | - | 0.7 | - | 0.7 | ns |
| t _W | pulse width | data inputs | | 20 | - | 20 | - | 20 | - | ns |
| f _{data} | data rate | | | - | 50 | - | 50 | - | 50 | Mbps |
| $V_{CC(A)} =$ | 2.5 V ± 0.2 V | | | | | | | | | |
| t _{PHL} | HIGH to LOW propagation delay | A to B | | - | 3.2 | - | 3.3 | - | 3.4 | ns |
| t _{PLH} | LOW to HIGH propagation delay | A to B | | - | 3.5 | - | 4.1 | - | 4.4 | ns |
| t _{PHL} | HIGH to LOW propagation delay | B to A | | - | 3.0 | - | 3.6 | - | 4.3 | ns |
| t _{PLH} | LOW to HIGH propagation delay | B to A | | - | 2.5 | - | 1.6 | - | 0.7 | ns |
| t _{en} | enable time | OE to A; B | | - | 200 | - | 200 | - | 200 | ns |
| t _{dis} | disable time | OE to A; no external load | [2] | - | 20 | - | 20 | - | 20 | ns |
| | | OE to B; no external load | [2] | - | 20 | - | 20 | - | 20 | ns |
| | | OE to A | | - | 200 | - | 200 | - | 200 | ns |
| | | OE to B | | - | 200 | - | 200 | - | 200 | ns |
| t _{TLH} | LOW to HIGH | A port | | 2.8 | 7.4 | 2.6 | 6.6 | 1.8 | 6.2 | ns |
| | output transition time | B port | | 3.2 | 8.3 | 2.9 | 7.9 | 2.4 | 6.8 | ns |

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| Symbol | Parameter | Conditions | | | | ۷c | C(B) | | | Unit |
|----------------------|-------------------------------|---------------------------|-----|-----------------|-----|---------|---------|---------------|-----|------|
| | | | - | $2.5~V\pm0.2~V$ | | 3.3 V : | ± 0.3 V | 5.0 V ± 0.5 V | | |
| | | | | Min | Max | Min | Max | Min | Max | |
| t _{THL} | HIGH to LOW | A port | | 1.9 | 5.7 | 1.9 | 5.5 | 1.8 | 5.3 | ns |
| | output transition time | B port | | 2.2 | 7.8 | 2.4 | 6.7 | 2.6 | 6.6 | ns |
| t _{sk(o)} | output skew time | between channels | [3] | - | 0.7 | - | 0.7 | - | 0.7 | ns |
| t _W | pulse width | data inputs | | 20 | - | 20 | - | 20 | - | ns |
| f _{data} | data rate | | | - | 50 | - | 50 | - | 50 | Mbp |
| V _{CC(A)} = | 3.3 V ± 0.3 V | | | | | | | | | |
| t _{PHL} | HIGH to LOW propagation delay | A to B | | - | - | - | 2.4 | - | 3.1 | ns |
| t _{PLH} | LOW to HIGH propagation delay | A to B | | - | - | - | 4.2 | - | 4.4 | ns |
| t _{PHL} | HIGH to LOW propagation delay | B to A | | - | - | - | 2.5 | - | 3.3 | ns |
| t _{PLH} | LOW to HIGH propagation delay | B to A | | - | - | - | 2.5 | - | 2.6 | ns |
| t _{en} | enable time | OE to A; B | | - | - | - | 200 | - | 200 | ns |
| t _{dis} | disable time | OE to A; no external load | [2] | - | - | - | 15 | - | 15 | ns |
| | | OE to B; no external load | [2] | - | - | - | 15 | - | 15 | ns |
| | | OE to A | | - | - | - | 260 | - | 260 | ns |
| | | OE to B | | - | - | - | 200 | - | 200 | ns |
| t _{TLH} | LOW to HIGH | A port | | - | - | 2.3 | 5.6 | 1.9 | 5.9 | ns |
| | output transition time | B port | | - | - | 2.5 | 6.4 | 2.1 | 7.4 | ns |
| t _{THL} | THL HIGH to LOW | A port | | - | - | 2.0 | 5.4 | 1.9 | 5.0 | ns |
| | output transition time | B port | | - | - | 2.3 | 7.4 | 2.4 | 7.6 | ns |
| t _{sk(o)} | output skew time | between channels | [3] | - | - | - | 0.7 | - | 0.7 | ns |
| t _W | pulse width | data inputs | | - | - | 20 | - | 20 | - | ns |
| f _{data} | data rate | | | - | - | - | 50 | - | 50 | Mbp |

 Table 10.
 Dynamic characteristics for temperature range -40 °C to +85 °C^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6; for wave forms see Figure 4 and Figure 5.

[1] t_{en} is the same as t_{PZL} and t_{PZH} .

 t_{dis} is the same as t_{PLZ} and t_{PHZ} .

[2] Delay between OE going LOW and when the outputs are actually disabled.

[3] Skew between any two outputs of the same package switching in the same direction.

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| Symbol | Parameter | Conditions | | V _{CC(B)} | | | | | | Unit |
|------------------------------|-------------------------------|---------------------------|------------|--------------------|------|-------------------|------|-------------------|------|------|
| | | | | 2.5 V ± 0.2 V | | $3.3 V \pm 0.3 V$ | | $5.0 V \pm 0.5 V$ | | |
| | | | | Min | Мах | Min | Max | Min | Max | |
| / _{CC(A)} = | 1.8 V ± 0.15 V | | | | | | | | | |
| PHL | HIGH to LOW propagation delay | A to B | | - | 5.8 | - | 5.9 | - | 7.3 | ns |
| PLH | LOW to HIGH propagation delay | A to B | | - | 8.5 | - | 8.5 | - | 8.8 | ns |
| PHL | HIGH to LOW propagation delay | B to A | | - | 5.5 | - | 5.7 | - | 5.9 | ns |
| PLH | LOW to HIGH propagation delay | B to A | | - | 6.7 | - | 5.7 | - | 0.7 | ns |
| en | enable time | OE to A; B | | - | 200 | - | 200 | - | 200 | ns |
| t _{dis} | disable time | OE to A; no external load | [2] | - | 30 | - | 30 | - | 30 | ns |
| | | OE to B; no external load | [2] | - | 30 | - | 30 | - | 30 | ns |
| | | OE to A | | - | 250 | - | 250 | - | 250 | ns |
| | | OE to B | | - | 220 | - | 220 | - | 220 | ns |
| t _{TLH} LOW to HIGH | A port | | 3.2 | 11.9 | 2.3 | 11.7 | 1.8 | 9.5 | ns | |
| | output transition time | B port | | 3.3 | 13.5 | 2.7 | 11.4 | 2.7 | 9.5 | ns |
| t _{THL} | HIGH to LOW | A port | | 2.0 | 7.4 | 1.9 | 7.5 | 1.7 | 16.7 | ns |
| output transition time | | B port | | 2.9 | 9.5 | 2.8 | 9.4 | 2.8 | 12.5 | ns |
| sk(o) | output skew time | between channels | <u>[3]</u> | - | 0.8 | - | 0.8 | - | 0.8 | ns |
| W | pulse width | data inputs | | 20 | - | 20 | - | 20 | - | ns |
| data | data rate | | | - | 50 | - | 50 | - | 50 | Mb |
| / _{CC(A)} = | 2.5 V ± 0.2 V | | | | | | | | | |
| PHL | HIGH to LOW propagation delay | A to B | | - | 4.0 | - | 4.2 | - | 4.3 | ns |
| PLH | LOW to HIGH propagation delay | A to B | | - | 4.4 | - | 5.2 | - | 5.5 | ns |
| PHL | HIGH to LOW propagation delay | B to A | | - | 3.8 | - | 4.5 | - | 5.4 | ns |
| PLH | LOW to HIGH propagation delay | B to A | | - | 3.2 | - | 2.0 | - | 0.9 | ns |
| en | enable time | OE to A; B | | - | 200 | - | 200 | - | 200 | ns |
| dis | disable time | OE to A; no external load | [2] | - | 25 | - | 25 | - | 25 | ns |
| | | OE to B; no external load | [2] | - | 25 | - | 25 | - | 25 | ns |
| | | OE to A | | - | 220 | - | 220 | - | 220 | ns |
| | | OE to B | | - | 220 | - | 220 | - | 220 | ns |
| TLH | LOW to HIGH | A port | | 2.8 | 9.3 | 2.6 | 8.3 | 1.8 | 7.8 | ns |
| | output transition time | B port | | 3.2 | 10.4 | 2.9 | 9.7 | 2.4 | 8.3 | ns |

Table 11. Dynamic characteristics for temperature range -40 °C to +125 °C^[1]

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| Symbol | Parameter | Conditions | | V _{CC(B)} | | | | | | Unit |
|----------------------|-------------------------------|---------------------------|------------|--------------------|-----|-------|---------|-----------------------------------|-----|------|
| | | | | $2.5~V\pm0.2~V$ | | 3.3 V | ± 0.3 V | $5.0 \text{ V} \pm 0.5 \text{ V}$ | | |
| | | | | Min | Max | Min | Max | Min | Max | |
| t _{THL} | HIGH to LOW | A port | | 1.9 | 7.2 | 1.9 | 6.9 | 1.8 | 6.7 | ns |
| | output transition time | B port | | 2.2 | 9.8 | 2.4 | 8.4 | 2.6 | 8.3 | ns |
| t _{sk(o)} | output skew time | between channels | <u>[3]</u> | - | 0.8 | - | 0.8 | - | 0.8 | ns |
| t _W | pulse width | data inputs | | 20 | - | 20 | - | 20 | - | ns |
| f _{data} | data rate | | | - | 50 | - | 50 | - | 50 | Mbps |
| V _{CC(A)} = | 3.3 V ± 0.3 V | | | | | | | | | |
| t _{PHL} | HIGH to LOW propagation delay | A to B | | - | - | - | 3.0 | - | 3.9 | ns |
| t _{PLH} | LOW to HIGH propagation delay | A to B | | - | - | - | 5.3 | - | 5.5 | ns |
| t _{PHL} | HIGH to LOW propagation delay | B to A | | - | - | - | 3.2 | - | 4.2 | ns |
| t _{PLH} | LOW to HIGH propagation delay | B to A | | - | - | - | 3.2 | - | 3.3 | ns |
| t _{en} | enable time | OE to A; B | | - | - | - | 200 | - | 200 | ns |
| t _{dis} | disable time | OE to A; no external load | [2] | - | - | - | 20 | - | 20 | ns |
| | | OE to B; no external load | [2] | - | - | - | 20 | - | 20 | ns |
| | | OE to A | | - | - | - | 280 | - | 280 | ns |
| | | OE to B | | - | - | - | 220 | - | 220 | ns |
| t _{TLH} | LOW to HIGH | A port | | - | - | 2.3 | 7.0 | 1.9 | 7.4 | ns |
| | output transition time | B port | | - | - | 2.5 | 8.0 | 2.1 | 9.3 | ns |
| t _{THL} | HIGH to LOW | A port | | - | - | 2.0 | 6.8 | 1.9 | 6.3 | ns |
| | output transition time | B port | | - | - | 2.3 | 9.3 | 2.4 | 9.5 | ns |
| t _{sk(o)} | output skew time | between channels | [3] | - | - | - | 0.8 | - | 0.8 | ns |
| tw | pulse width | data inputs | | - | - | 20 | - | 20 | - | ns |
| f _{data} | data rate | | | - | - | - | 50 | - | 50 | Mbps |

Table 11. Dynamic characteristics for temperature range $-40 \text{ °C to } +125 \text{ °C} \frac{[1]}{2}$... continued

iours 4 and Figure F

[1] t_{en} is the same as t_{PZL} and t_{PZH} .

 t_{dis} is the same as t_{PLZ} and $t_{\text{PHZ}}.$

[2] Delay between OE going LOW and when the outputs are actually disabled.

[3] Skew between any two outputs of the same package switching in the same direction.

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13. Waveforms





Table 12. Measurement points^{[1][2]}

| Supply voltage | Input | Output | Output | | | | | |
|-------------------------------|---------------------|---------------------|--------------------------|--------------------------|--|--|--|--|
| V _{cco} | V _M | V _M | V _X | V _Y | | | | |
| $1.8~V\pm0.15~V$ | 0.5V _{CCI} | 0.5V _{CCO} | V _{OL} + 0.15 V | V _{OH} – 0.15 V | | | | |
| $2.5~\text{V}\pm0.2~\text{V}$ | 0.5V _{CCI} | 0.5V _{CCO} | V _{OL} + 0.15 V | V _{OH} – 0.15 V | | | | |
| $3.3~V\pm0.3~V$ | 0.5V _{CCI} | 0.5V _{CCO} | V _{OL} + 0.3 V | V _{OH} – 0.3 V | | | | |
| $5.0~\text{V}\pm0.5~\text{V}$ | 0.5V _{CCI} | 0.5V _{CCO} | V _{OL} + 0.3 V | V _{OH} – 0.3 V | | | | |

[1] V_{CCI} is the supply voltage associated with the input.

[2] V_{CCO} is the supply voltage associated with the output.

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Table 13. Test data

| Supply voltage | | Input | | Load | V _{EXT} | | | |
|--------------------|--------------------|--------------------------------|-----------------|-------|-------------------|-------------------------------------|-------------------------------------|---|
| V _{CC(A)} | V _{CC(B)} | V <mark>[^[1]</mark> | ∆t/∆V | CL | RL ^[2] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ^[3]} |
| 1.65 V to 3.6 V | 2.3 V to 5.5 V | V _{CCI} | \leq 1.0 ns/V | 15 pF | 50 kΩ, 1 MΩ | open | open | 2V _{CCO} |

[1] V_{CCI} is the supply voltage associated with the input.

[2] For measuring data rate, pulse width, propagation delay and output rise and fall measurements, $R_L = 1 M\Omega$; for measuring enable and disable times, $R_L = 50 K\Omega$.

[3] V_{CCO} is the supply voltage associated with the output.

14. Application information

14.1 Applications

Voltage level-translation applications. The NTS0102-Q100 can be used in point-to-point applications to interface between devices or systems operating at different supply voltages. The device is primarily targeted at I²C or 1-wire which use open-drain drivers. It may also be used in applications where push-pull drivers are connected to the ports although the NTB0102-Q100 may be more suitable.



14.2 Architecture

The architecture of the NTS0102-Q100 is shown in Figure 8. The device does not require an extra input signal to control the direction of data flow from A to B or B to A.



The NTS0102-Q100 is a "switch" type voltage translator, it employs two key circuits to enable voltage translation:

- 1. A pass-gate transistor (N-channel) that ties the ports together.
- An output edge-rate accelerator that detects and accelerates rising edges on the I/O pins.

The gate bias voltage of the pass gate transistor (T3) is set at approximately one threshold voltage above the V_{CC} level of the low-voltage side. During a LOW-to-HIGH transition, the output one-shot accelerates the output transition by switching on the PMOS transistors (T1, T2). This action bypasses the 10 k Ω pull-up resistors and increases current drive capability. The one-shot is activated once the input transition reaches approximately V_{CCI}/2. It is de-activated approximately 50 ns after the output reaches V_{CCO}/2. During the acceleration time, the driver output resistance is between approximately 50 Ω and 70 Ω . To avoid signal contention and minimize dynamic I_{CC}, before applying a signal in the opposite direction, wait for the one-shot circuit to turn-off. Pull-up resistors are included in the device for DC current sourcing capability.

14.3 Input driver requirements

As the NTS0102-Q100 is a switch type translator, properties of the input driver directly affect the output signal. The external open-drain or push-pull driver applied to an I/O, determines the static current sinking capability of the system. The max data rate, HIGH-to-LOW output transition time (t_{THL}) and propagation delay (t_{PHL}) are dependent upon the output impedance and edge-rate of the external driver. The limits provided for these parameters in the data sheet assume a driver with output impedance below 50 Ω is used.

14.4 Output load considerations

The maximum lumped capacitive load that can be driven is dependent upon the one-shot pulse duration. In cases with very heavy capacitive loading, there is a risk that the output does not reach the positive rail within the one-shot pulse duration.

To avoid excessive capacitive loading and to ensure correct triggering of the one-shot, use short trace lengths and low capacitance connectors on NTS0102-Q100 PCB layouts. To ensure low impedance termination and avoid output signal oscillations and one-shot retriggering, limit the length of the PCB trace. The PCB trace should be such that the round-trip delay of any reflection is within the one-shot pulse duration (approximately 50 ns).

14.5 Power-up

During operation $V_{CC(A)}$ must never be higher than $V_{CC(B)}$, however during power-up $V_{CC(A)} \ge V_{CC(B)}$ does not damage the device, so either power supply can be ramped up first. There is no special power-up sequencing required. The NTS0102-Q100 includes circuitry that disables all output ports when either $V_{CC(A)}$ or $V_{CC(B)}$ is switched off.

14.6 Enable and disable

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state. The disable time (t_{dis} with no external load) indicates the delay between when OE goes LOW and when outputs actually become disabled. The enable time (t_{en}) indicates the amount of time to allow for one one-shot circuit to become operational after OE is taken HIGH. To ensure the high-impedance OFF-state during power-up or power-down, pin OE should be tied to GND through a pull-down resistor. The current-sourcing capability of the driver determines the minimum value of the resistor.

14.7 Pull-up or pull-down resistors on I/Os lines

Each A port I/O has an internal 10 k Ω pull-up resistor to $V_{CC(A)}$. Each B port I/O has an internal 10 k Ω pull-up resistor to $V_{CC(B)}$. If a smaller value of pull-up resistor is required, an external resistor must be added parallel to the internal 10 k Ω . The reduction in the value of the pull-up resistor affects the V_{OL} level. When OE goes LOW, the internal pull-ups of the NTS0102-Q100 are disabled.

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15. Package outline



Fig 9. Package outline SOT505-2 (TSSOP8)

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XSON8: plastic extremely thin small outline package; no leads;

Fig 10. Package outline SOT996-2 (XSON8)

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16. Abbreviations

| Table 14. | Abbreviations |
|------------------|---|
| Acronym | Description |
| CMOS | Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| GPIO | General Purpose Input Output |
| HBM | Human Body Model |
| l ² C | Inter-Integrated Circuit |
| MIL | Military |
| MM | Machine Model |
| PCB | Printed Circuit Board |
| PMOS | Positive Metal Oxide Semiconductor |
| SMBus | System Management Bus |
| UART | Universal Asynchronous Receiver Transmitter |
| UTLP | Ultra Thin Leadless Package |

17. Revision history

| Table 15. Revision history | | | | | | | |
|----------------------------|--------------|--------------------|---------------|------------|--|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | |
| NTS0102_Q100 v.1 | 20130227 | Product data sheet | - | - | | | |

18. Legal information

18.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
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